

**FEATURES**

- Very High Current Transfer Ratio, 500% Min.
- Isolation Test Voltage, 5300 V<sub>RMS</sub>
- High Isolation Resistance, 10<sup>11</sup> Ω Typical
- Low Coupling Capacitance
- Standard Plastic DIP Package
- Underwriters Lab File #E52744
- VDE 0884 Available with Option 1

**Maximum Ratings (Each Channel)**
**Emitter**

Peak Reverse Voltage ..... 3.0 V  
 Continuous Forward Current ..... 60 mA  
 Power Dissipation at 25°C ..... 100 mW  
 Derate Linearly from 25°C ..... 1.33 mW/°C

**Detector**

Collector-Emitter Breakdown Voltage ..... 30 V  
 Collector (Load) Current ..... 125 mA  
 Power Dissipation at 25°C Ambient ..... 150 mW  
 Derate Linearly from 25°C ..... 2.0 mW/°C

**Package**

Isolation Test Voltage (between emitter and detector refer to standard climate 23°C/50%RH, DIN 50014)  
 $t=1.0$  sec ..... 5300 V<sub>RMS</sub>  
 Creepage ..... ≥7.0 mm  
 Clearance ..... ≥7.0 mm  
 Comparative Tracking Index per DIN IEC 112/VDE303, part 1 ..... ≥175  
 Isolation Resistance

$V_{IO}=500V$ ,  $T_A=25^\circ C$  .....  $R_{IO}=10^{12} \Omega$   
 $V_{IO}=500V$ ,  $T_A=100^\circ C$  .....  $R_{IO}=10^{11} \Omega$

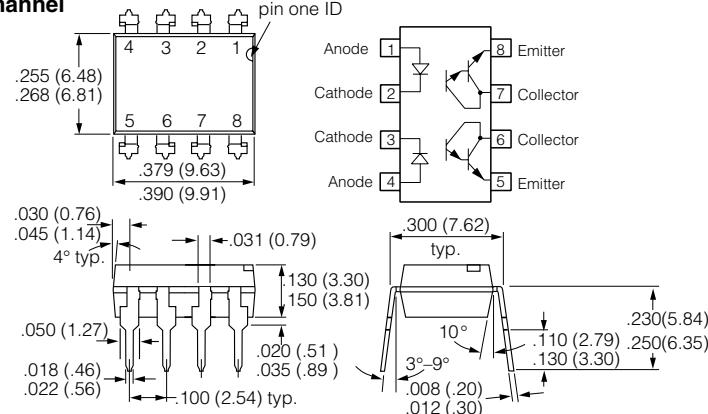
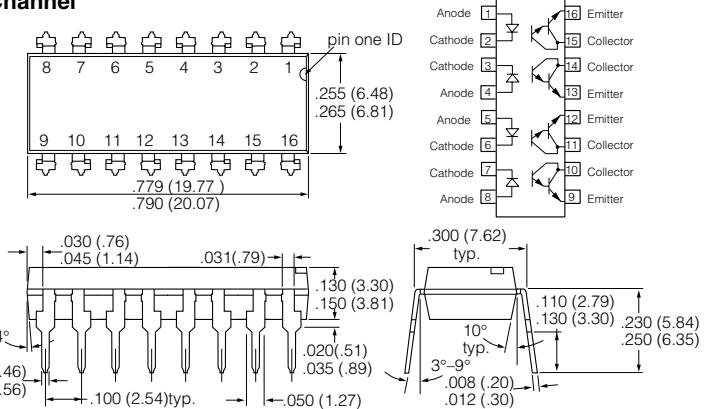
Total Dissipation at 25°C Ambient  
 ILD32 ..... 400 mW  
 ILQ32 ..... 500 mW

Derate Linearly from 25°C  
 ILD32 ..... 5.33 mW/°C  
 ILQ32 ..... 6.67 mW/°C  
 Storage Temperature ..... -55°C to +150°C  
 Operating Temperature ..... -55°C to +100°C  
 Lead Soldering Time at 260°C ..... 10 sec.

**DESCRIPTION**

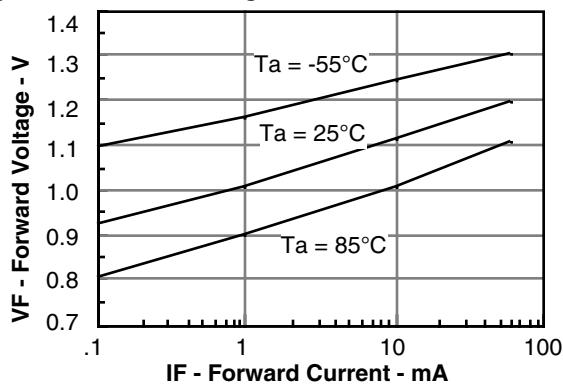
The ILD32/ILQ32 are optically coupled isolators with a Gallium Arsenide infrared LED and a silicon photodarlington sensor. Switching can be achieved while maintaining a high degree of isolation between driving and load circuits. These optocouplers can be used to replace reed and mercury relays with advantages of long life, high speed switching and elimination of magnetic fields.

The ILD32 has two isolated channels in a DIP package, and the ILQ32 has four channels. These devices can be used to replace 4N32s or 4N33s in applications calling for several single channel optocouplers on a board.

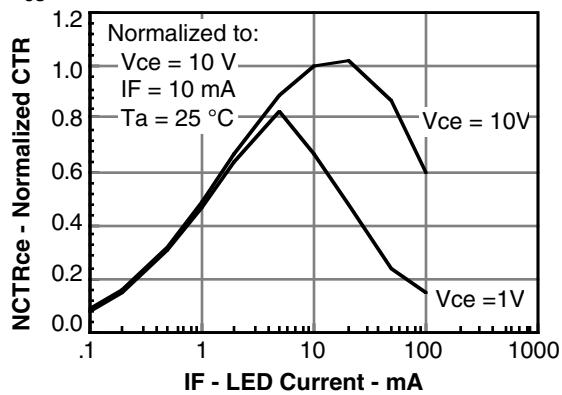
**Dimensions in inches (mm)**
**Dual Channel**

**Quad Channel**

**Table 1. Electrical Characteristics,  $T_A=25^\circ C$** 

Parameter	Symbol	Min.	Typ.	Max.	Unit	Condition
<b>Emitter</b>						
Forward Voltage	$V_F$	—	1.25	1.5	V	$I_F=10$ mA
Reverse Current	$I_R$	—	0.1	100	μA	$V_R=3.0$ V
Capacitance	$C_O$	—	25	—	pF	$V_R=0$ V
<b>Detector</b>						
Breakdown Voltage Collector-Emitter	$BV_{CEO}$	30	—	—	V	$I_C=100$ μA $I_F=0$
Breakdown Voltage Emitter-Collector	$BV_{ECO}$	5.0	10	—	V	$I_E=100$ μA
Collector-Emitter Leakage Current	$I_{CEO}$	—	1.0	100	nA	$V_{CE}=10$ V $I_F=0$
<b>Package</b>						
Current Transfer Ratio	CTR	500	—	—	%	$I_F=10$ mA $V_{CE}=10$ V
Collector Emitter Saturation Voltage	$V_{CEsat}$	—	—	1.0	V	$I_C=2.0$ mA $I_F=8.0$ mA
Isolation Capacitance	$C_{ISOL}$	—	0.5	—	pF	—
Turn-On Time	$t_{on}$	—	15	—	μs	$V_{CC}=10$ V $I_F=5.0$ mA $R_L=100$ Ω
Turn-Off Time	$t_{off}$	—	30	—	μs	

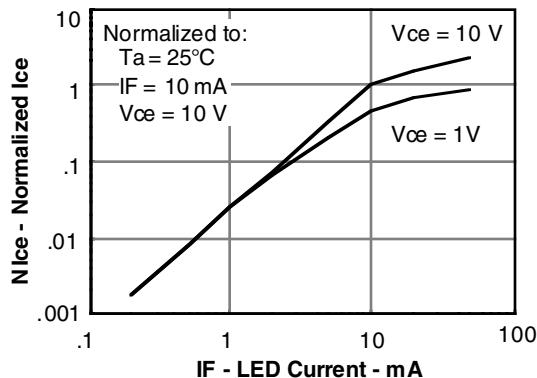
**Figure 1. Forward voltage versus forward current**



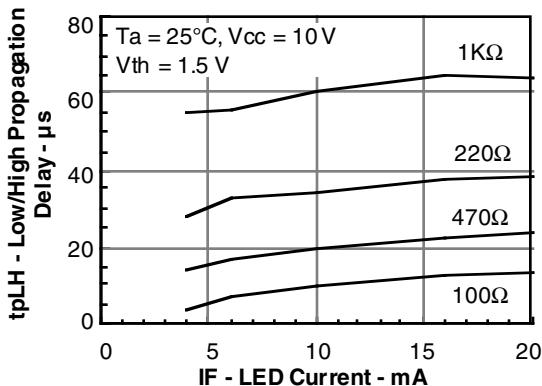
**Figure 2. Normalized non-saturated and saturated CTR<sub>ce</sub> at T<sub>A</sub>=25°C versus LED current**



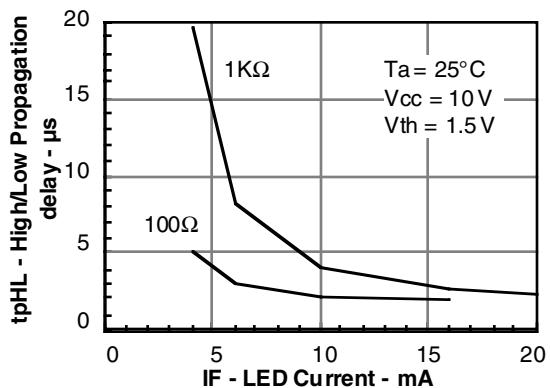
**Figure 3. Normalized non-saturated and saturated collector-emitter current versus LED current**



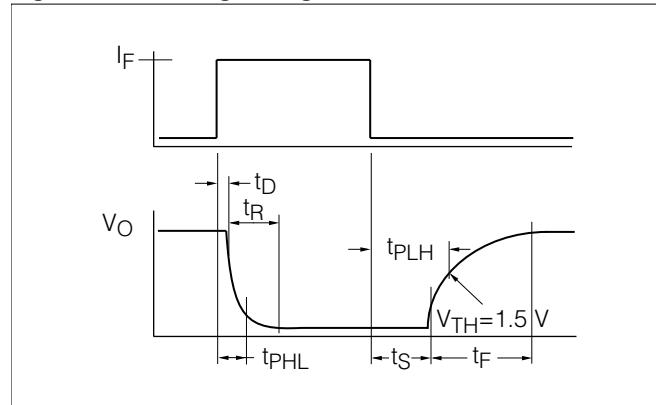
**Figure 4. Low to high propagation delay versus collector load resistance and LED current**



**Figure 5. High to low propagation delay versus collector load resistance and LED current**



**Figure 6. Switching timing**



**Figure 7. Switching schematic**

